

# International **IR** Rectifier

**30CTH02SPbF**  
**30CTH02-1PbF**

## Hyperfast Rectifier

### Features

- Hyperfast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature
- Lead-Free ("PbF" suffix)

$t_{tr} = 30\text{ns max.}$   
 $I_{F(AV)} = 30\text{Amp}$   
 $V_R = 200\text{V}$

### Description/ Applications

International Rectifier's 200V series are the state of the art Hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

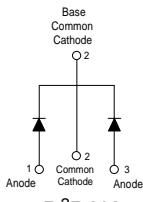
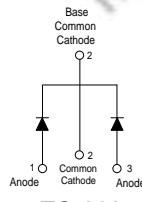
The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### Absolute Maximum Ratings

Parameters	Max	Units
$V_{RRM}$ Peak Repetitive Reverse Voltage	200	V
$I_{F(AV)}$ Average Rectified Forward Current $\text{@ } T_C = 159^\circ\text{C}$ Per Diode	15	A
Per Device	30	
$I_{FSM}$ Non Repetitive Peak Surge Current $\text{@ } T_J = 25^\circ\text{C}$	200	
$T_J, T_{STG}$ Operating Junction and Storage Temperatures	- 65 to 175	$^\circ\text{C}$

Case Styles	
 30CTH02SPbF  D <sup>2</sup> PAK	 30CTH02-1PbF  TO-262

**Electrical Characteristics @  $T_J = 25^\circ\text{C}$  (unless otherwise specified)**

Parameters	Min	Typ	Max	Units	Test Conditions
$V_{BR}, V_r$ Breakdown Voltage, Blocking Voltage	200	-	-	V	$I_R = 100\mu\text{A}$
$V_F$ Forward Voltage	-	0.92	1.05	V	$I_F = 15\text{A}, T_J = 25^\circ\text{C}$
	-	0.78	0.85	V	$I_F = 15\text{A}, T_J = 125^\circ\text{C}$
$I_R$ Reverse Leakage Current	-	-	10	$\mu\text{A}$	$V_R = V_R \text{ Rated}$
	-	5	300	$\mu\text{A}$	$T_J = 125^\circ\text{C}, V_R = V_R \text{ Rated}$
$C_T$ Junction Capacitance	-	57	-	pF	$V_R = 200\text{V}$
$L_S$ Series Inductance	-	8	-	nH	Measured lead to lead 5mm from package body

**Dynamic Recovery Characteristics @  $T_C = 25^\circ\text{C}$  (unless otherwise specified)**

Parameters	Min	Typ	Max	Units	Test Conditions
$t_{rr}$ Reverse Recovery Time	-	-	35	ns	$I_F = 1\text{A}, dI_F/dt = 50\text{A}/\mu\text{s}, V_R = 30\text{V}$
	-	-	30		$I_F = 1\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}, V_R = 30\text{V}$
	-	26	-		$T_J = 25^\circ\text{C}$
	-	40	-		$T_J = 125^\circ\text{C}$
$I_{RRM}$ Peak Recovery Current	-	2.8	-	A	$T_J = 25^\circ\text{C}$
	-	6.0	-		$T_J = 125^\circ\text{C}$
$Q_{rr}$ Reverse Recovery Charge	-	37	-	nC	$T_J = 25^\circ\text{C}$
	-	120	-		$T_J = 125^\circ\text{C}$

**Thermal - Mechanical Characteristics**

Parameters	Min	Typ	Max	Units
$T_J$ Max. Junction Temperature Range	- 65	-	175	°C
$T_{Stg}$ Max. Storage Temperature Range	- 65	-	175	
$R_{thJC}$ Thermal Resistance, Junction to Case Per Diode	-	-	1.1	°C/W
	-	2.0	-	
	-	0.07	-	
Weight	6.0	-	12	Kg-cm
	5.0	-	10	lbf.in
Mounting Torque	30CTH02S	Case style D <sup>2</sup> Pak		
	30CTH02-1	Case style TO-262		

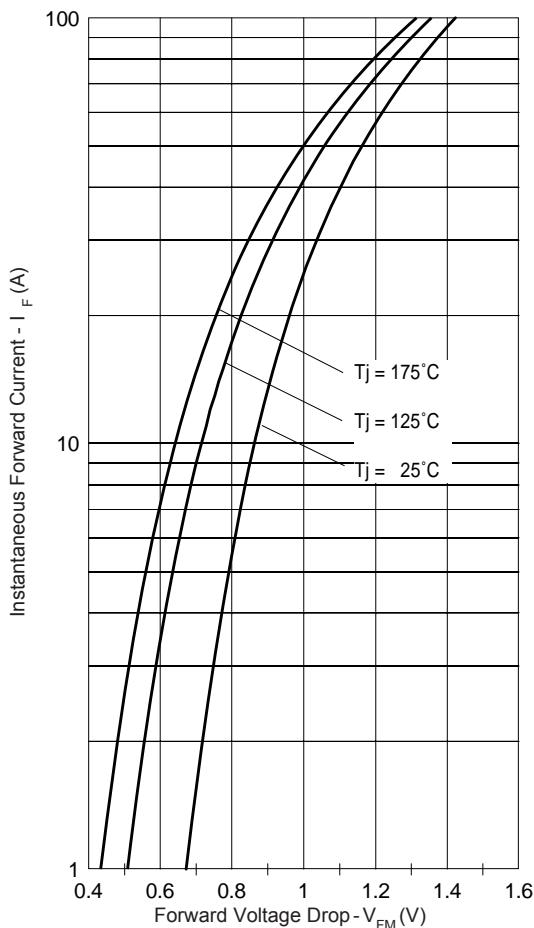


Fig. 1 - Typical Forward Voltage Drop Characteristics

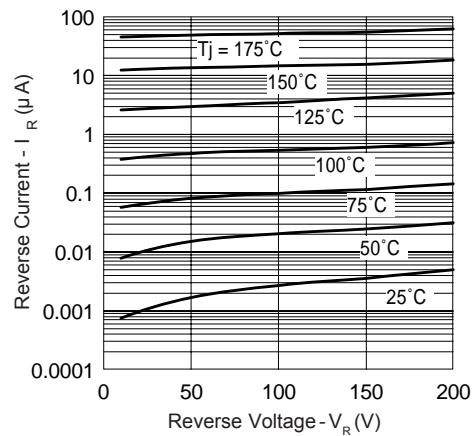


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

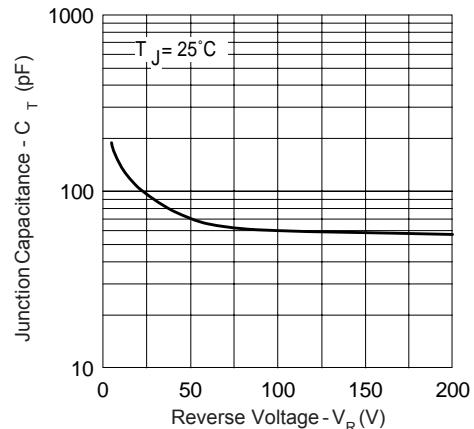


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

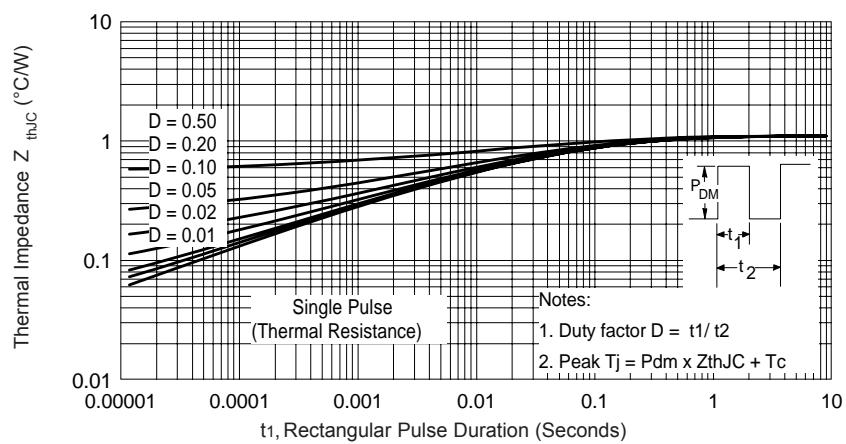
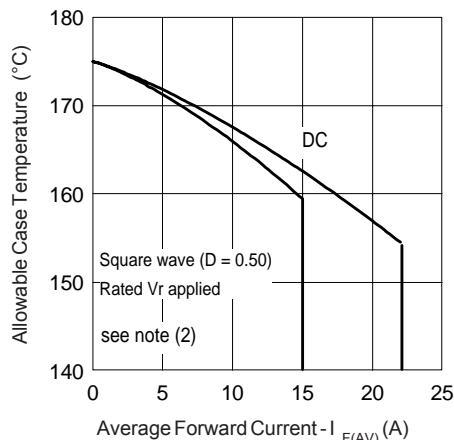
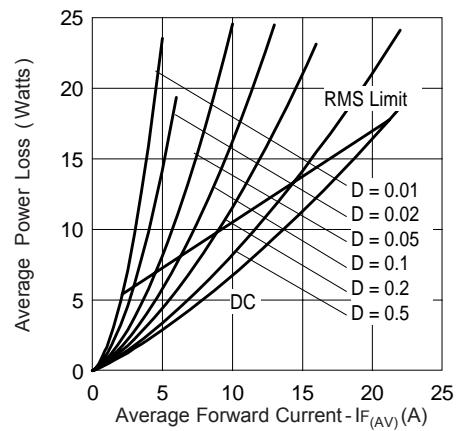


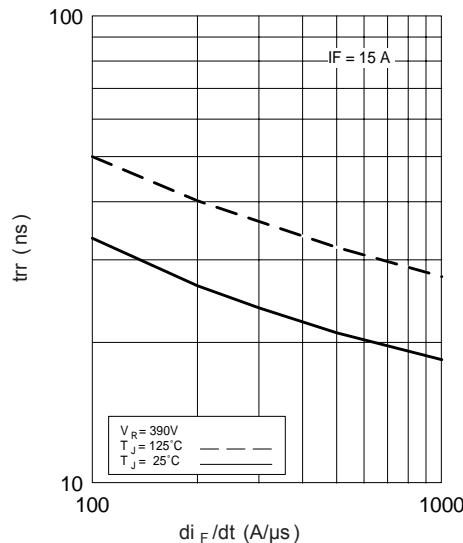
Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics



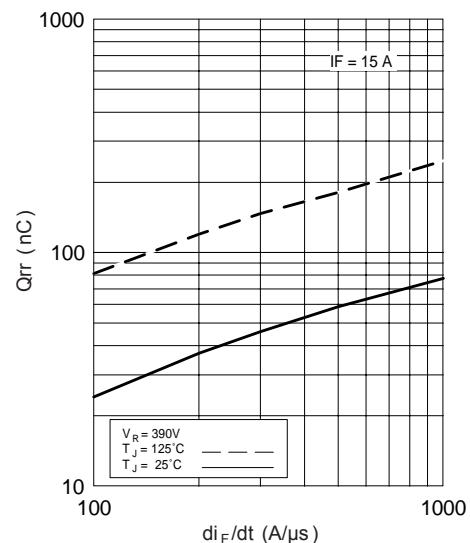
**Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current**



**Fig. 6 - Forward Power Loss Characteristics**



**Fig. 7 - Typical Reverse Recovery vs.  $di_F/dt$**



**Fig. 8 - Typical Stored Charge vs.  $di_F/dt$**

(2) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$  (see Fig. 8);  
 $Pd_{REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1-D)$ ;  $I_R @ V_{R1} = \text{rated } V_R$

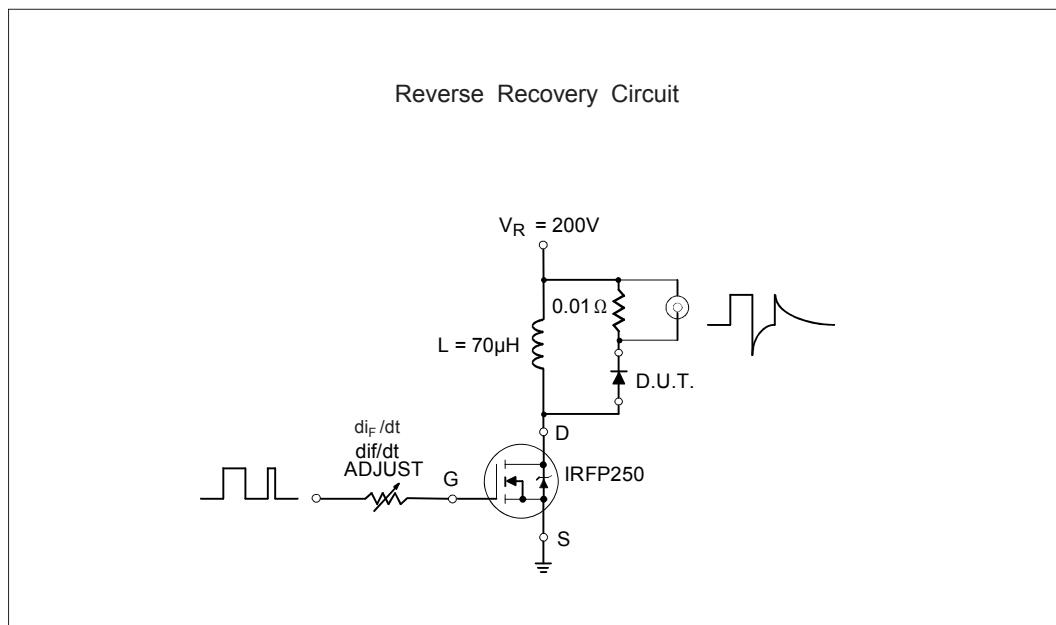


Fig. 9- Reverse Recovery Parameter Test Circuit

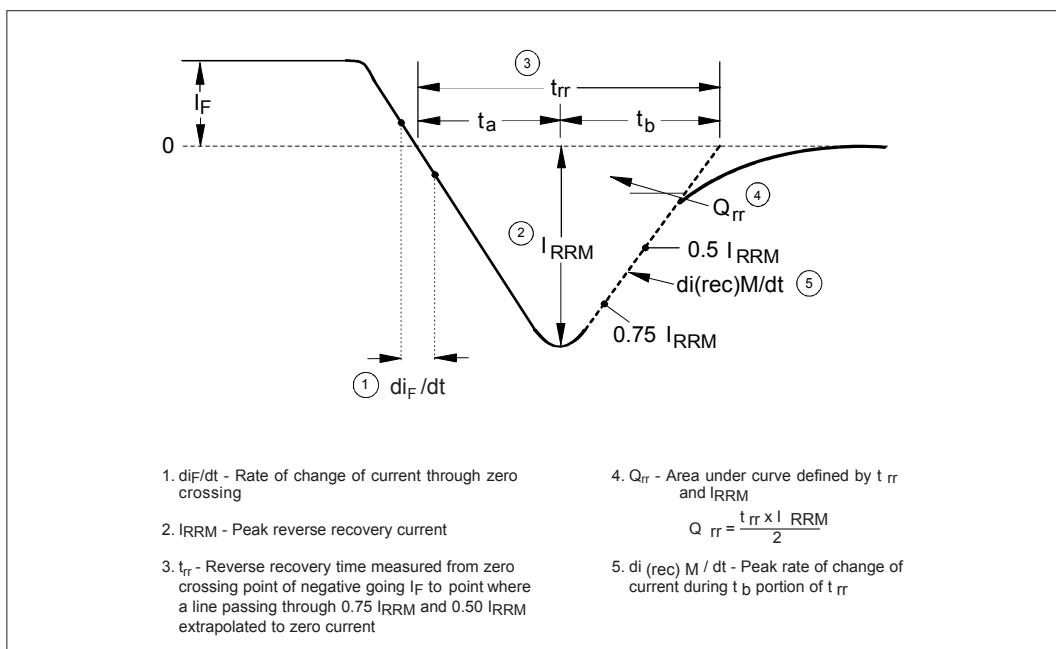
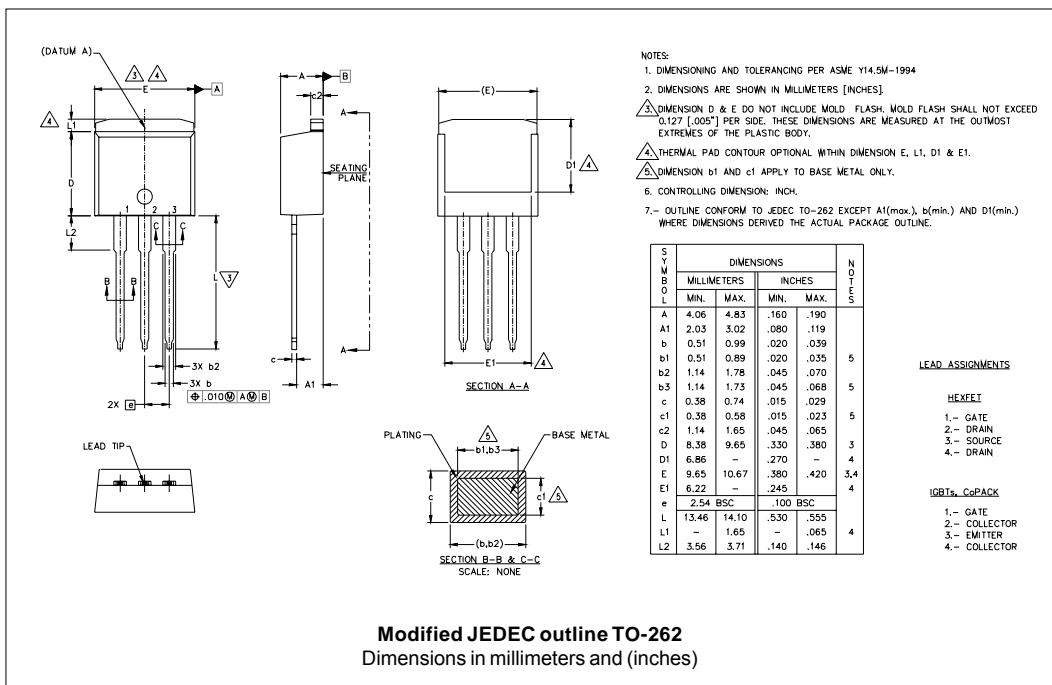
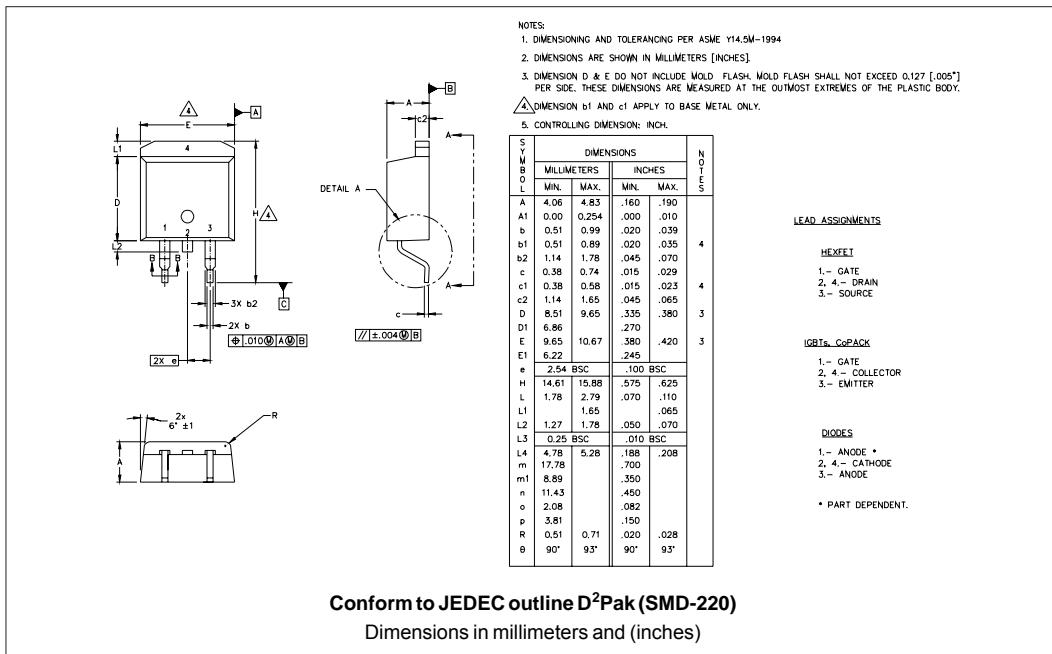
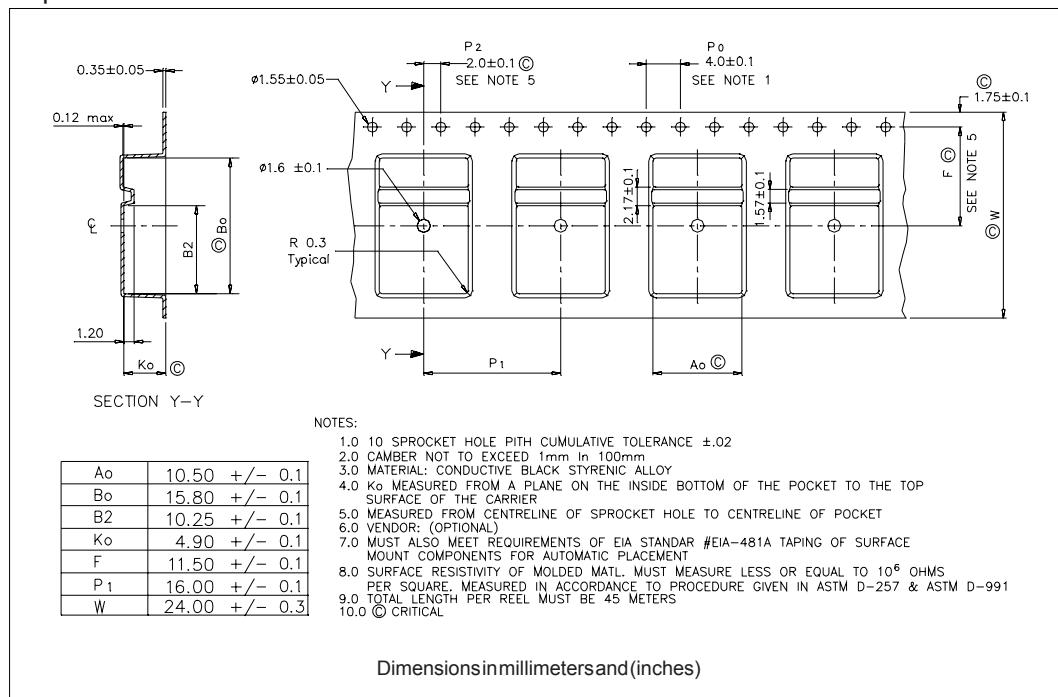


Fig. 10 - Reverse Recovery Waveform and Definitions

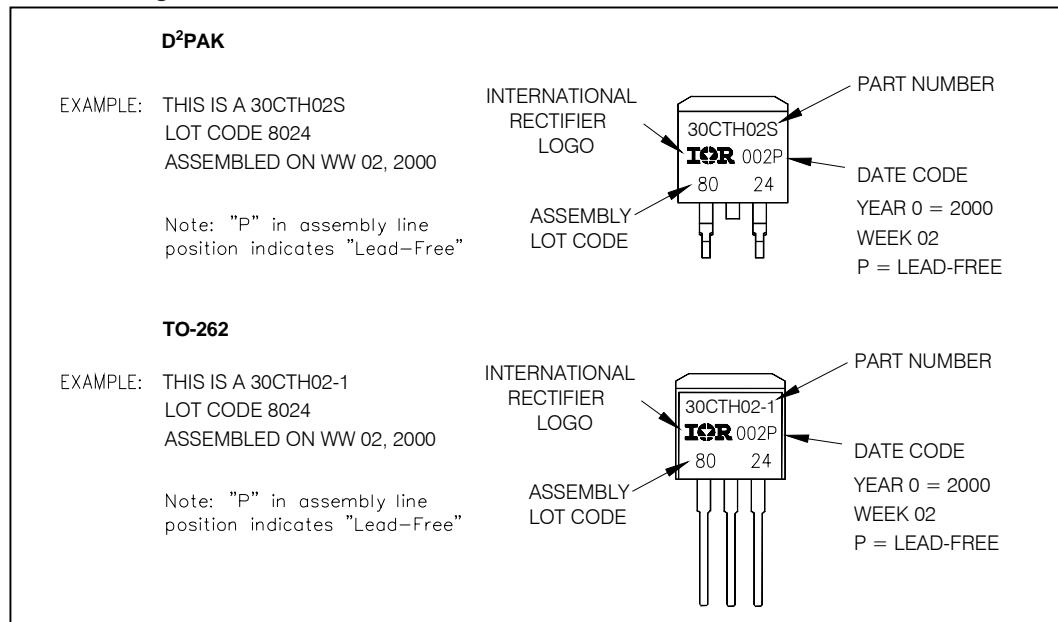
## Outline Table



### Tape & Reel Information



### Part Marking Information



## Ordering Information Table

Device Code	30	C	T	H	02	S	TRL	PbF
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)
<b>1</b>	-	Current Rating (30A)						
<b>2</b>	-	C = Common Cathode						
<b>3</b>	-	T = TO-220, D <sup>2</sup> Pak						
<b>4</b>	-	H = Hyperfast Rectifier						
<b>5</b>	-	Voltage Rating (02 = 200V)						
<b>6</b>	-	• S = D <sup>2</sup> Pak • -1 = TO-262						
<b>7</b>	-	• none = Tube (50 pieces) • TRL = Tape & Reel (Left Oriented, for D <sup>2</sup> PAk package) • TRR = Tape & Reel (Right Oriented, for D <sup>2</sup> PAk package)						
<b>8</b>	-	• none = Standard Production • PbF = Lead-Free						

Data and specifications subject to change without notice.  
 This product has been designed and qualified for Industrial Level and Lead-Free.  
 Qualification Standards can be found on IR's Web site.

 International  
 Rectifier

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